



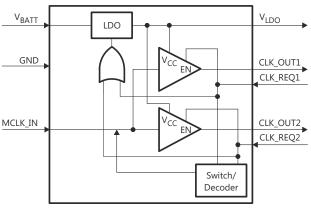
CDC3RL02 Low Phase-Noise Two-Channel Clock Fan-Out Buffer

1 Features

- Low Additive Noise:
 - 149dBc/Hz at 10kHz Offset Phase Noise
 - 0.37ps (RMS) Output Jitter
- Limited Output Slew Rate for EMI Reduction (1ns to 5ns Rise/Fall Time for 10pF to 50pF Loads)
- Adaptive Output Stage Controls Reflection
- Regulated 1.8V Externally Available I/O Supply
- Ultra-Small 8-bump YFP 0.4mm Pitch WCSP $(0.8 \text{mm} \times 1.6 \text{mm})$
- ESD Performance Exceeds JESD 22
 - 2000V Human-Body Model (A114-A)
 - 1000V Charged-Device Model (JESD22-C101-A Level III)

2 Applications

- **Cellular Phones**
- Global Positioning Systems (GPS)
- Wireless LAN
- FM Radio •
- WiMAX
- W-BT



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Simplified Block Diagram

3 Description

The CDC3RL02 is a two-channel clock fan-out buffer and is designed for use in portable end-equipment, such as mobile phones, that require clock buffering with minimal additive phase noise and fan-out capabilities. The device buffers a single clock source, such as a temperature compensated crystal oscillator (TCXO) to multiple peripherals. The device has two clock request inputs (CLK REQ1 and CLK REQ2), each input can enable a single clock output.

The CDC3RL02 accepts square or sine waves at the master clock input (MCLK IN), eliminating the need for an AC coupling capacitor. The smallest acceptable sine wave is a 0.3V signal (peak-to-peak). CDC3RL02 is designed to offer minimal channel-to-channel skew, additive output jitter, and additive phase noise. The adaptive clock output buffers offer controlled slewrate over a wide capacitive loading range which minimizes EMI emissions, maintains signal integrity, and minimizes ringing caused by signal reflections on the clock distribution lines.

The CDC3RL02 has an integrated Low-Drop-Out (LDO) voltage regulator which accepts input voltages from 2.3V to 5.5V and outputs 1.8V, 50mA. This 1.8V supply is externally available to provide regulated power to peripheral devices such as a TCXO.

The CDC3RL02 is offered in a 0.4mm pitch die size ball grid array (DSBGA) package (0.8mm × 1.6mm), also known as wafer-level chip-scale (WCSP) package, and is optimized for very low standby current consumption.

PART NUMBER ⁽¹⁾	PART NUMBER (1) PACKAGE	
CDC3RL02	YFP (DSBGA, 8)	0.80mm × 1.60mm

For more information, see Section 11. (1)

The package size (length × width) is a nominal value and (2) includes pins, where applicable.





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4 Device Comparison

Table 4-1. Device Comparison

T _A	PACKAGE (1)	PACKAGE (1) ORDERABLE PART NUMBER	
-40°C to 85°C	YFP	CDC3RL02BYFPR	Yes
-40°C to 85° C	YFP	CDC3RL02YFPR	No

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) CSP (DSBGA) devices manufactured with backside coating have an increased resistance to cracking due to the increased physical strength of the package. Devices with backside coating are highly encouraged for new designs.

5 Pin Configuration and Functions

	1	2
А	(<u>Â</u>)	(Â2)
В	(B)	(B2)
С	(C)	(C2)
D	(Đ)	(D2)

Figure 5-1. YFP Package 8-Pin DSBGA Top View

Table 5-1. Pin Functions

PIN		Type ⁽¹⁾	DESCRIPTION	
NAME	NO.	Type	DESCRIPTION	
V _{BATT}	A1	I	Input to internal LDO	
CLK_OUT1	A2	0	Clock output 1	
V _{LDO}	B1	0	1.8V I/O supply for CDC3RL02 and external TCXO	
CLK_REQ1	B2	I	lock request 1 (from peripheral) for Clock output 1	
MCLK_IN	C1	I	laster clock input	
CLK_REQ2	C2	I	lock request 2 (from peripheral) for Clock output 2	
GND	D1	-	Ground	
CLK_OUT2	D2	0	Clock output 2	

(1) I = Input, O = Output

Table 5-2. YFP Package Pin Assignments

	1	2
A	V _{BATT}	CLK_OUT1
В	V _{LDO}	CLK_REQ1
С	MCLK_LIN	CLK_REQ2
D	GND	CLK_OUT2

6 Specifications

6.1 Absolute Maximum Ratings

			MIN	MAX	UNIT
V _{BATT}	Voltage range ⁽²⁾		-0.3	7	V
	Voltage range ⁽³⁾	CLK_REQ_1/2, MCLK_IN	-0.3	V _{BATT} + 0.3	V
	voltage range.	V _{LDO} , CLK_OUT_1/2 ⁽²⁾	-0.3	V _{BATT} + 0.3	V
I _{IK}	Input clamp current at V _{BATT} , CLK_REQ_1/2, and MCLK_IN	V ₁ < 0		-50	mA
lo	Continuous output current	CLK_OUT1/2		±20	mA
	Continuous current through GND, V_{BAT}	TT, V _{LDO}		±50	mA
TJ	Operating virtual junction temperature		-40	150	°C
T _A	Operating ambient temperature range		-40	85	°C
T _{stg}	Storage temperature range		-55	150	°C

over operating free-air temperature range, unless otherwise noted. (1)

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) The input negative-voltage and output voltage ratings can be exceeded if the input and output current ratings are observed.

(3) All voltage values are with respect to network ground pin.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V
		Machine Model	200	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500V HBM is possible with the necessary precautions.

(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250V CDM is possible with the necessary precautions.

6.3 Recommended Operating Conditions

See (1)

			MIN	MAX	UNIT
V _{BATT}	Input voltage to internal LDO		2.3	5.5	V
VI	Input voltage	MCLK_IN, CLK_REQ1/2	0	1.89	V
Vo	Output voltage	CLK_OUT1/2	0	1.8	V
V _{IH}	High-level input voltage	CLK_REQ1/2	1.3	1.89	V
VIL	Low-level input voltage	CLK_REQ1/2	0	0.5	V
I _{OH}	High-level output current, DC current		-8		mA
I _{OL}	Low-level output current, DC current			8	mA

 All unused inputs of the device must be held at V_{CC} or GND to verify proper device operation. See the *Implications of Slow or Floating* CMOS Inputs application note.



6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		CDC3RL02	UNIT	
		YFP (TSSOP)		
		8 PINS	-	
R _{θJA}	Junction-to-ambient thermal resistance	107.8	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	1.3	°C/W	
R _{θJB}	Junction-to-board thermal resistance	18.1	°C/W	
ΨJT	Junction-to-top characterization parameter	4.5	°C/W	
Ψ _{JB}	Junction-to-board characterization parameter	18.1	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CON	DITIONS	MIN	TYP	MAX	UNIT	
LDO		1				I		
V _{OUT}	LDO output voltage	I _{OUT} = 50mA		1.71	1.8	1.89	V	
C _{LDO}	External load capacitance			1		10	μF	
I _{OUT(SC)}	Short circuit output current	$R_L = 0\Omega$			100		mA	
I _{OUT(PK)}	Peak output current	V _{BATT} = 2.3V, V _{LDO} = V _{OUT} – 5	5%			100	mA	
PSR	Power supply rejection	V _{BATT} = 2.3V, I _{OUT} = 2mA,	f _{IN} = 217Hz and 1kHz	60			dB	
FOR	Power supply rejection	$v_{BATT} - 2.3v, i_{OUT} - 211A,$	f _{IN} = 3.25MHz	40				
+	LDO startup time	V_{BATT} = 2.3V, C_{LDO} = 1µF, CLK_REQ_n to V_{IH} = 1.71V			0.2		ms	
t _{su}		V_{BATT} = 5.5V, C_{LDO} = 10µF, CLK_REQ_n to V _{IH} = 1.71V				1	115	
POWER	CONSUMPTION							
I _{SB}	Standby current	Device in standby (all $V_{CLK_{RE}}$	_{Q_n} = 0V)		0.2	1	μA	
I _{CCS}	Static current consumption	Device active but not switching	9		0.4	1	mA	
I _{OB}	Output buffer average current	f _{IN} = 26MHz, C _{LOAD} = 50pF			4.2		mA	
C _{PD}	Output power dissipation capacitance	f _{IN} = 26MHz				44	pF	
MCLK_I	N INPUT							
lı	MCLK_IN, CLK_REQ_1/2 leakage current	V _I = V _{IH} or GND				1	μA	
CI	MCLK_IN capacitance	f _{IN} = 26MHz			4.75		pF	
RI	MCLK_IN impedance	f _{IN} = 26MHz			6		kΩ	
f _{IN}	MCLK_IN frequency range			10	26	100	MHz	
MCLK_I	N LVCMOS SOURCE							
			1kHz offset		-140			
	Additive phase paize	 f _{IN} = 26MHz, t _r /t _f ≤ 1ns	10kHz offset		-149		dBc/Hz	
	Additive phase noise	$\eta_N = 2010112, \eta_r/\eta = 1115$	100kHz offset		-153	aBC/H	UDC/112	
			1MHz offset		-148			
	Additive jitter	f _{IN} = 26MHz, V _{PP} = 0.8V, BW =	= 10MHz to 5MHz		0.37		ps (rms)	
t _{DL}	MCLK_IN to CLK_OUT_n propagation delay				11		ns	
DCL	Output duty cycle	f _{IN} = 26MHz, DC _{IN} = 50%		45%	50%	55%		

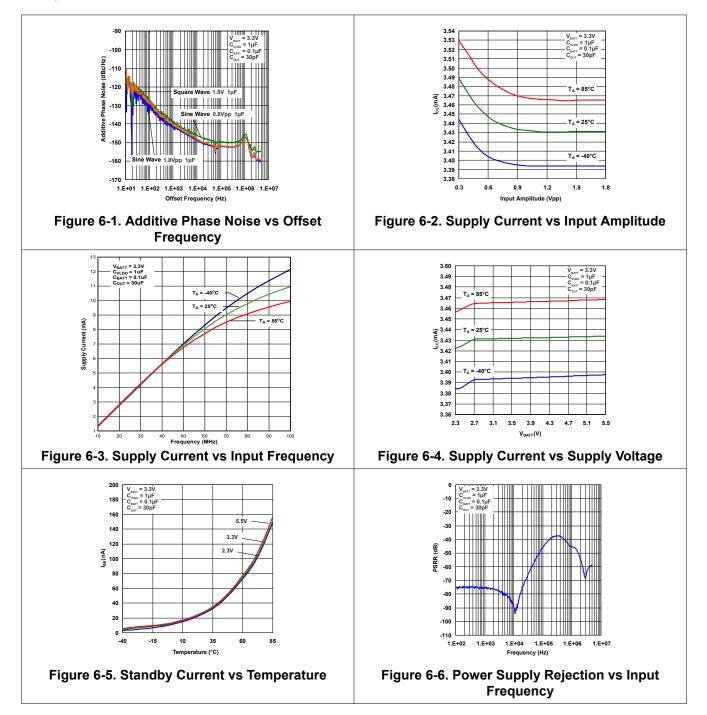


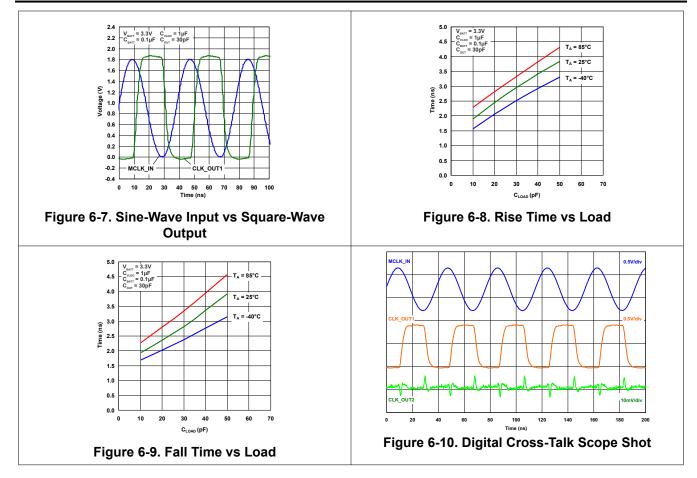
over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CON	IDITIONS	MIN	TYP	MAX	UNIT
MCLK	IN SINUSOIDAL SOURCE						
V _{MA}	Input amplitude			0.3		1.8	V
			1kHz offset		-141		
		f = 0.0011 = 1/2 = 4.01/2	10kHz offset		-149		
		f_{IN} = 26MHz, V_{MA} = 1.8 V_{PP}	100kHz offset		-152		
			1MHz offset		-148		
	Additive phase noise		1kHz offset		-139		dBc/Hz
			10kHz offset		-146		
		$f_{IN} = 26MHz, V_{MA} = 0.8V_{PP}$	100kHz offset		-150		
			1MHz offset		-146		
	Additive jitter	f _{IN} = 26MHz, V _{MA} = 1.8V _{PP} , E	3W = 10MHz to 5MHz		0.41		ps (RMS
t _{DS}	MCLK_IN to CLK_OUT_1/2 propagation delay				12		ns
DCs	Output duty cycle	f _{IN} = 26MHz, V _{MA} > 1.8V _{PP}		45%	50%	55%	
CLK_C	OUT_N OUTPUTS			I			
t _r	20% to 80% rise time	$C_L = 10 pF$ to $50 pF$		1		5.2	ns
t _f	20% to 80% fall time	$C_L = 10 pF$ to 50 pF		1		5.2	ns
t _{sk}	Channel-to-channel skew	$C_{L} = 10 \text{pF} \text{ to } 50 \text{pF} (C_{L1} = C_{L2})$	2)	-0.5		0.5	ns
V	Lligh lovel output veltage	I_{OH} = -100µA, reference to V	LDO	-0.1			
V _{OH}	High-level output voltage	I _{OH} = -8mA		1.2	2		V
V	Low lovel output veltage	I _{OL} = 20μΑ				0.2	v
V _{OL}	Low-level output voltage	I _{OL} = 8mA				0.55	v



6.6 Typical Characteristics







7 Detailed Description

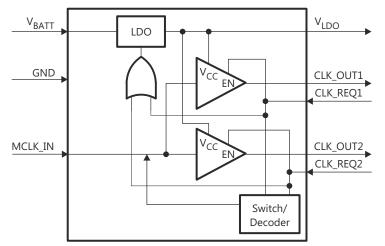
7.1 Overview

The CDC3RL02 is a two-channel clock fan-out buffer and is designed for use in portable end-equipment, such as mobile phones, that require clock buffering with minimal additive phase noise and fan-out capabilities. The device buffers a single master clock, such as a temperature compensated crystal oscillator (TCXO) to multiple peripherals. The device has two clock request inputs (CLK_REQ1 and CLK_REQ2), each of which enable a single clock output.

The CDC3RL02 accepts square or sine waves at the master clock input (MCLK_IN), eliminating the need for an AC coupling capacitor. The smallest acceptable sine wave is a 0.3V signal (peak-to-peak). CDC3RL02 is designed to offer minimal channel-to-channel skew, additive output jitter, and additive phase noise. The adaptive clock output buffers offer controlled slew-rate over a wide capacitive loading range which minimizes EMI emissions, maintains signal integrity, and minimizes ringing caused by signal reflections on the clock distribution lines.

The CDC3RL02 has an integrated Low-Drop-Out (LDO) voltage regulator which accepts input voltages from 2.3V to 5.5V and outputs 1.8V, 50mA. This 1.8V supply is externally available to provide regulated power to peripheral devices such as a TCXO.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Low Additive Noise

The CDC3RL02 features –149dBc/Hz at 10kHz offset phase noise and 0.37ps (RMS) of output jitter, to provide low noise buffered signals.

7.3.2 Regulated 1.8V Externally Available I/O Supply

The CDC3RL02 allows users to connect to the output of the internal LDO, for providing power to other ICs. For more information, refer to *LDO*.

7.3.3 Ultra-Small 8-bump YFP 0.4mm Pitch WCSP Package

Using the ultra-small YFP package, the CDC3RL02 is very small and allows the device to be placed on a board with minimum work.



7.4 Device Functional Modes

Table 7-1 is the function table for CDC3RL02.

INPUTS			OUT	PUTS		
CLK_REQ1 ⁽¹⁾	CLK_REQ2 ⁽¹⁾	MCLK_IN	CLK_OUT1	CLK_OUT2		
L	L	X	L	L		
L	Н	CLK	L	CLK		
Н	L	CLK	CLK	L		
Н	Н	CLK	CLK	CLK		

Table 7-1. Function Table

(1) If a CLK_OUT is always enabled, tying the CLK_REQ pin to an external 1.8V source (not VLDO) is acceptable.

8 Application and Implementation

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

Note

8.1 Application Information

8.1.1 Input Clock Squarer

Figure 8-1 shows the input stage of the CDC3RL02. The input signal at MCLK_IN can be a square wave or sine wave. C_{MCLK} is an internal AC coupling capacitor that allows a direct connection from the TCXO to the CDC3RL02 without an external capacitor.

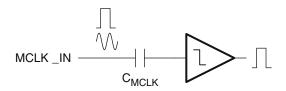


Figure 8-1. Input Stage With Internal AC Coupling Capacitor

Any external component added in the series path of the clock signal potentially adds phase noise and jitter. The error source associated with the internal decoupling capacitor is included in the specification of the CDC3RL02. The recommended clock frequency band of the CDC3RL02 is 10MHz to 80MHz for specified functionality. All performance metrics are specified at 26MHz. The lowest acceptable sinusoidal signal amplitude is $0.8V_{PP}$ for specified performance. Amplitudes as low as $0.3V_{PP}$ are acceptable but with reduced phase-noise and jitter performance.

8.1.2 Output Stage

Each output drives 1.8V LVCMOS levels. Adaptive output buffers limit the rise/fall time of the output to within 1ns to 5ns with load capacitance between 10pF and 50pF. Fast slew rates introduce EMI into the system. Each output buffer limits EMI by keeping the rise/fall time above 1ns. Slow rise/fall times can induce additive phase noise and duty cycle errors in the load device. The output buffer limits these errors by keeping the rise/fall time below 5ns. In addition, the output stage dynamically alters impedance based on the instantaneous voltage level of the output. This dynamic change limits reflections keeping the output signal monotonic during transitions. Each output is active low when not requested to avoid false clocking of the load device.

8.1.3 LDO

A low noise 1.8V LDO is integrated to provide the I/O supply for the output buffers. The LDO output is externally available to power a clock source such as a TCXO. A clean supply is provided to the clock buffers and the clock

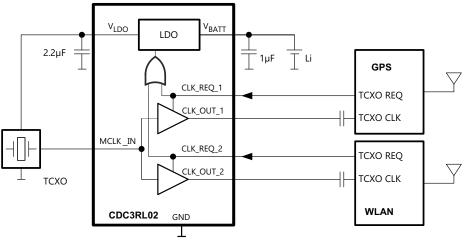


source for optimum phase noise performance. The input range of the LDO allows the device to be powered directly from a single cell Li battery. The LDO is enabled by either of the CLK_REQ_N signals. When disabled, the device enters a low power shutdown mode consuming less than 1µA from the battery. The LDO requires an output decoupling capacitor in the range of 1µF to 10µF with an equivalent series resistance (ESR) of at least 0.1 Ω for compensation and high-frequency PSR. This capacitor must stay within the specified range for capacitance and ESR over the entire operating temperature range. A ceramic capacitor can be used if a small external resistance is added in series with the capacitor to increase the effective ESR. An input bypass capacitor of 1µF or larger is recommended.



8.2 Typical Application

The CDC3RL02 is designed for use in mobile applications as shown in Figure 8-2. In this example, a single low noise TCXO system clock source is buffered to drive a mobile GPS receiver and WLAN transceiver. Each peripheral independently requests an active clock by asserting a single clock request line (CLK_REQ_1 or CLK_REQ_2). When both clock request lines are inactive, the CDC3RL02 enters a low current shutdown mode. In this mode, the LDO output, CLK_OUT_1, and CLK_OUT_2 are pulled to GND and the TCXO is not powered.



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Figure 8-2. Mobile Application

When either peripheral requests the clock, the CDC3RL02 enables the LDO and powers the TCXO. The TCXO output (square wave, sine wave, or clipped sine wave) is converted to a square wave and buffered to the requested output.

8.2.1 Design Requirements

For the typical application, the user must know the following parameters.

Table 8-1. Design Parameters

PARAMETER	DESCRIPTION	EXAMPLE VALUE
V _{BATT}	Input voltage from battery or power supply	3.7V
MCLK_IN	Input frequency from a TCXO	26MHz

8.2.2 Detailed Design Procedure

The designer must verify that all parameters are within the ranges specified in *Recommended Operating Conditions.*

Each device which receives a clock output from the CDC3RL02 must have the CLK request pin connected to the appropriate CLK_REQ pin on the CDC3RL02. This pin enables the output buffer when a device requests the clock signal.

Control of the clock outputs is possible by using a GPIO from a controller to control the CLK_REQ pins.

If one of the outputs is unused, then tie the CLK_REQ and CLK_OUT pins to ground. If the user wants a CLK_OUT pin always enabled, tie the paired CLK_REQ pin to an external 1.8V source (not V_{LDO} because the LDO output is not enabled until at least one CLK_REQ pin is high).



8.2.3 Application Curve

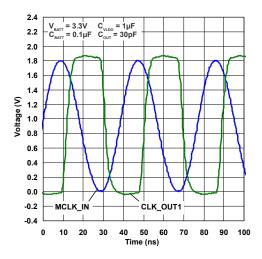


Figure 8-3. Sine Wave Input vs Output

8.3 Power Supply Recommendations

General power supply recommendations are to be considered for the CDC3RL02. These include:

- Decoupling capacitors placed close to the V_{BATT} pin of typical values (1µF)
- V_{BATT} be within the recommended voltage range

8.4 Layout

8.4.1 Layout Guidelines

To provide reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors must be used on power supplies and must be placed as close as possible to the V_{BATT} pin
- · Short trace-lengths must be used to avoid excessive loading
- For improved performance on the clock output lines, use a ground trace on the sides of the clock trace to minimize crosstalk and EMI

8.4.2 Layout Example

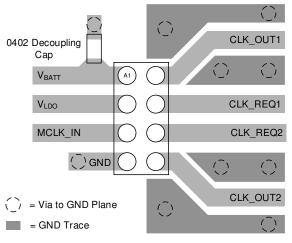


Figure 8-4. Example Layout for YFP Package



9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

· Texas Instruments, AN-2028 LMH2191 Evaluation Board, compatible EVM user's guide

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments. All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	Changes from Revision G (November 2022) to Revision H (October 2024)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Updated the Electrical Characteristics for increased 100MHz MCLK_IN maximum frequency	<mark>5</mark>

С	hanges from Revision F (August 2019) to Revision G (November 2022)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Changed MCLK_IN frequency maximum value from: 54MHz to: 80MHz	<mark>5</mark>
•	Changed the x-axis range in Figure 6-3	7
•	Moved the Power Supply Recommendations and Layout sections to the Application and Implementation section.	n

С	hanges from Revision E (August 2018) to Revision F (August 2019)	Page
•	Changed MCLK_IN frequency maximum value from: 52MHz to: 54MHz	5



CDC3RL02 SCHS371H – NOVEMBER 2009 – REVISED OCTOBER 2024

SCHS37TH - NOVEMBER 2009 - REVISED OCTOBER 2024

С	Changes from Revision D (April 2017) to Revision E (August 2018)	Page
•	Changed V _{LDO} test conditions to V _{IH} conditions in the <i>Electrical Characteristics</i> table	5
•	Added a tablenote to the Function Table	10
•	Added content to the LDO section	10
•	Changed the last sentence in the Detailed Design Procedure section	12
	-	

С	hanges from Revision C (January 2016) to Revision D (April 2017)	Page
•	Updated clock request descriptions in the Pin Functions table	3
•	Added Receiving Notification of Documentation Updates section	14

С	Changes from Revision B (December 2015) to Revision C (January 2016)	
•	Added the Device Comparison	3

С	hanges from Revision A (September 2015) to Revision B (November 2015)	Page
•	Added Thermal Information table, Overview, Feature Description section, Power Supply Recommenda section, and Layout section.	tions 1

С	hanges from Revision * (November 2009) to Revision A (September 2015)	Page
•	Formatted document to new standards	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CDC3RL02BYFPR	ACTIVE	DSBGA	YFP	8	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	4LN	Samples
CDC3RL02YFPR	ACTIVE	DSBGA	YFP	8	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	4LN	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

22-Aug-2024



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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDC3RL02BYFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1
CDC3RL02YFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1



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PACKAGE MATERIALS INFORMATION

25-Sep-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDC3RL02BYFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0
CDC3RL02YFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0

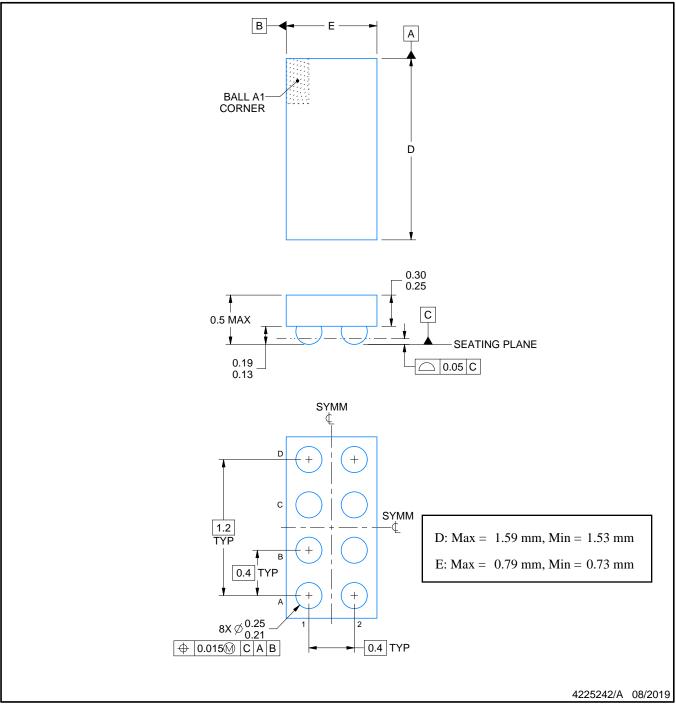
YFP0008



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

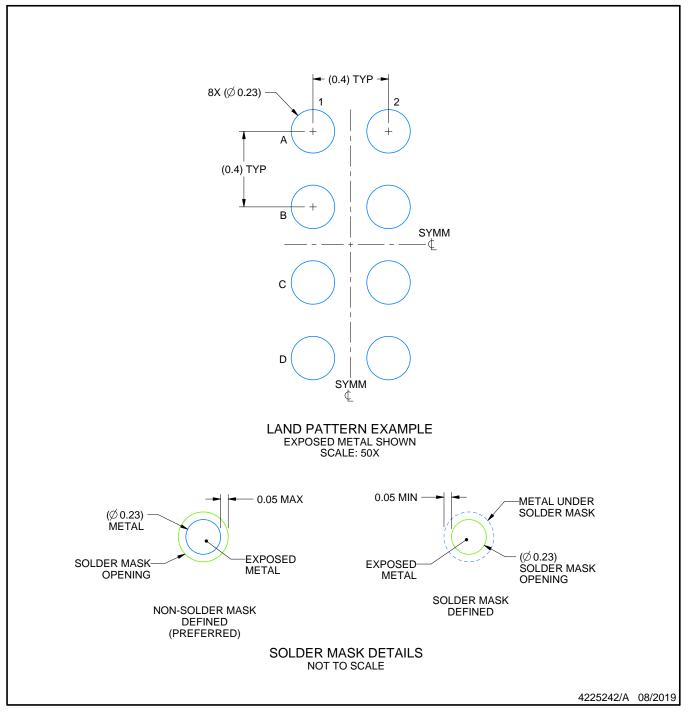


YFP0008

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).

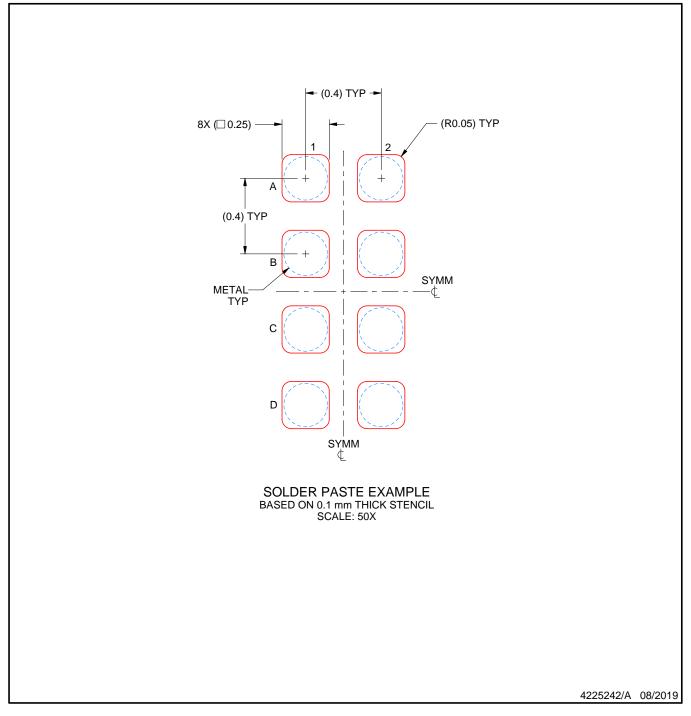


YFP0008

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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